Commensurability Oscillations of Hole-Flux Composite Fermions

D. Kamburov, M. Shayegan, L. N. Pfeiffer, K. W. West, and K. W. Baldwin

Department of Electrical Engineering, Princeton University, Princeton, New Jersey 08544, USA

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We report the observation of commensurability oscillations of hole-flux composite fermions near a filling factor of $\nu=1/2$ in a high-mobility two-dimensional hole system confined to a GaAs quantum well and subjected to a weak, strain-induced, unidirectional periodic potential modulation. The oscillations, which are consistent with ballistic transport of fully spin-polarized composite fermions in a weak periodic effective magnetic field, are surprisingly strong and exhibit up to third-order minima. We extract a ballistic mean-free path of about 0.1 μ m for the hole-flux composite fermions.

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In the presence of a strong perpendicular magnetic field and at very low temperatures, two-dimensional (2D) interacting carriers minimize their energy by capturing an even number of flux quanta and creating new particles called composite fermions (CFs) [1–3]. When a Landau level is exactly half filled, e.g., at a filling factor of $\nu = 1/2$, the flux attachment cancels the external magnetic field B = $B_{1/2}$ completely, leaving the CFs in zero effective field. At and near half fillings, the CFs form a Fermi sea with its own Fermi contour and behave analogously to their zero-field counterparts in an effective field given by $B^* = B - B_{1/2}$. The quasiclassical orbits of CFs are thus expected to exhibit geometric resonances near $\nu = 1/2$ when their size equals the length scale of an external potential disturbance, similar to what is seen at low magnetic fields. Such resonances were indeed observed for CFs and provided a direct confirmation of the validity of the CF picture [4–7].

CF Fermi contours were probed in a number of later experiments in which a small periodic potential modulation was introduced in high-quality 2D electron systems [8–12]. In such experiments, one expects oscillations in the magnetoresistance, signalling the commensurability of the CF quasiclassical cyclotron orbit diameter with multiple integers of the period of the potential modulation. The observed magnetoresistance features around $\nu = 1/2$, however, were not clear oscillations but rather two weak minima, one on each side of $\nu = 1/2$, corresponding to the first instance when the CF orbits became commensurate the modulation period [8-15]. More recent experiments have hinted at additional magnetoresistance minima near $\nu = 3/2$, although their positions and amplitudes are not entirely consistent with simple commensurability oscillations (COs) of CFs [16].

Here we report magnetoresistance measurements in a high-mobility GaAs 2D *hole* system (2DHS) subjected to a strain-induced, unidirectional, periodic potential modulation. The data exhibit clear signatures of ballistic transport of hole-flux CFs around $\nu = 1/2$ (Fig. 1): a deep *V*-shaped resistance dip centered at $\nu = 1/2$, followed by COs minima [labeled i = 1 and 2 in Fig. 1(d)] and shoulders of

higher resistance further away from $\nu=1/2$. The positions of the CO minima agree well with the commensurability condition for fully spin-polarized hole-flux CFs in a weak periodic *magnetic* field. Analysis of the envelope of the COs permits an estimation of the CF CO lifetime in a Dingle-factor-type plot and its direct comparison with CFs' quantum (Shubnikov–de Haas) and transport lifetimes.

Strain-induced lateral superlattice samples with different lattice periods were prepared from a 2DHS confined to a 175-A-wide GaAs quantum well grown via molecular beam epitaxy on a (001) GaAs substrate. The quantum well is located 131 nm below the surface and is flanked on both sides by 95-nm-thick Al_{0.24}Ga_{0.76}As spacer layers and C δ -doped layers. The 2DHS density at $T=0.3~{\rm K}$ is $p \simeq 1.5 \times 10^{11}~{\rm cm}^{-2}$, and the mobility is $\mu=$ 1.2×10^6 cm²/V s. We varied p by using an In back gate. Each sample had two Hall bars made by wet etching past the top doping layer. As illustrated in the Fig. 1(a) inset, half of each Hall bar was covered with a grating of a high-resolution negative electron-beam (e-beam) resist, while the other half was kept unpatterned as a reference. The e-beam resist grating creates surface strain, which in turn induces a periodic 2D density variation through the piezoelectric effect in GaAs [16–18]. The potential modulation is very gentle and preserves the very high quality of the samples, as it does not involve etching or gating. From our previous measurements, we estimate its amplitude to be only 1–5% of the 2D holes' Fermi energy [18]. The periods of the e-beam resist gratings were a = 100, 150,175, 200, 225, 250, and 300 nm. Measurements were made in a ³He refrigerator with a base temperature of $\simeq 0.3$ K by using low-frequency lock-in techniques.

In the CF picture, the effective magnetic field B^* felt by the CFs is determined by the external magnetic field B and the CF density n through the expression $B^* = B - B_{1/2} = B - 2n\Phi_0$, where $B_{1/2}$ is the field at $\nu = 1/2$ and $\Phi_0 = h/e$ is the flux quantum [1–3]. In light of this expression, local density variations create strong local variations of B^* . Thus, a periodic density modulation leads to a periodicity

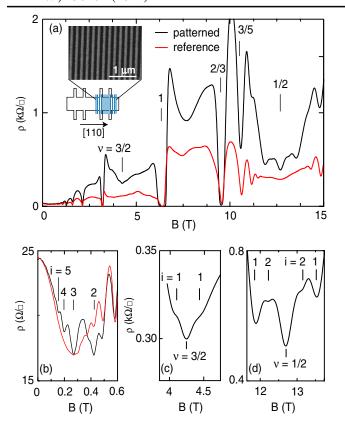


FIG. 1 (color online). (a) Magnetotransport data at T=0.3 K from the patterned (upper, black trace) and reference (lower, red trace) regions of the a=175 nm sample at a density of $p=1.53\times10^{11}$ cm⁻². The inset shows a high-quality scanning electron micrograph of the patterned region of the a=200 nm sample. (b) Low-field magnetoresistance of the patterned and reference regions. The patterned trace shows COs of holes. The values of the COs minima based on Eq. (2) are marked with indexed vertical lines. (c), (d) CF COs minima near $\nu=3/2$ and 1/2 and their positions according to Eq. (1) marked with vertical lines (i=1,2).

of B^* [8–15] and triggers $1/B^*$ -periodic oscillations of the magnetoresistance. The oscillations are quantitatively related to the commensurability between the CF cyclotron orbit diameter $2R_C^*$ and integer multiples of the modulation period. More precisely, the positions of resistance minima are given by the magnetic commensurability condition [10–12,19,20]:

$$\frac{2R_C^*}{a} = i + \frac{1}{4} \quad (i = 1, 2, 3, \ldots), \tag{1}$$

where $R_C^* = \hbar k_F^*/eB^*$ is the CF cyclotron radius; $k_F^* = \sqrt{4\pi p}$ is the CF Fermi wave vector and p is the CF density which is equal to the 2D hole density (p) for oscillations near $\nu = 1/2$. The above expression for k_F^* assumes a circular Fermi contour and complete spin polarization of CFs and is larger than its low-field (spin-degenerate) counterpart by a factor of $\sqrt{2}$.

Concentrating on the $\nu=1/2$ case, as seen in Figs. 1(a) and 1(d) the magnetoresistance trace from a sample with a patterned region (a=175 nm) has prominent CO features near this filling. First- and second-order (i=1,2) CF COs appear on both sides of $\nu=1/2$ followed by shoulders of rapidly rising resistance [14]. The positions of the i=1,2 CO minima based on Eq. (1) are marked with vertical lines in Fig. 1(d). A characteristic, deep, V-shaped resistance dip is also seen centered at $\nu=1/2$. It has been observed in previous experiments with electron samples and is attributed to channeled orbits [10,11] of CFs, similar to the resonant orbits of carriers occurring in modulated systems at low fields [21–23].

In our data we observe magnetoresistance features in the vicinity of $\nu=3/2$ as well. They are highlighted in Fig. 1(c) along with vertical lines indicating the positions of the first (i=1) CO minima predicted by Eq. (1) for fully spin-polarized CFs near $\nu=3/2$. The positions of these minima, given explicitly in endnote 18 of Ref. [16], are slightly asymmetric with respect to the field position of $\nu=3/2$ because of the dependence of the CF density on the magnetic field. Such asymmetry is observed in the data of Fig. 1(c) as well.

The patterned region's trace also shows pronounced resistance minima near zero magnetic field [Fig. 1(b)] signalling COs of 2D holes [18]. The field positions of the observed minima are consistent with the *electrostatic* CO condition [24–31]:

$$\frac{2R_C}{a} = i - \frac{1}{4} \quad (i = 1, 2, 3, \ldots). \tag{2}$$

The vertical indexed lines shown in Fig. 1(b) mark the positions of these minima based on Eq. (2) and assuming a circular, spin-degenerate Fermi contour with $k_F = \sqrt{2\pi p}$. As detailed in Ref. [18], the Fermi contours of the 2D holes in our samples are slightly warped; however, our CO data appear not to be sensitive to such warping and are consistent with circular contours. Note in Fig. 1(b) that the traces from both the patterned and reference regions exhibit Shubnikov–de Haas oscillations commencing at fields B > 0.3 T.

Returning to the $\nu=1/2$ data, in our experiments we find that the potential modulation period has an important effect on the appearance of the commensurability features near $\nu=1/2$. This dependence is illustrated in Fig. 2 for five periods between 150 and 250 nm. Data from the a=100 and 300 nm period samples are not plotted here, because the patterned regions of these samples do not show any sign of COs, and their magnetoresistance traces look very similar to those from the reference regions. In Fig. 2(a), the vertical lines mark the positions of the resistance minima in accordance with Eq. (1). For $B^*>0$ the expected positions of the CO minima match the observed positions well, while for $B^*<0$ the observed minima are shifted towards $B^*=0$. A similar shift was

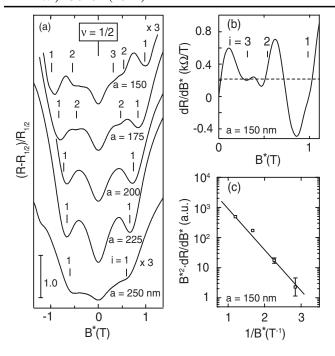


FIG. 2. (a) Magnetotransport data near $\nu=1/2$ given in terms of the differential resistance, normalized to the value of resistance at $\nu=1/2$, are shown as a function of the CF effective field (B^*) . The traces are offset vertically without changing the scale. The density of all samples is very close to 1.53×10^{11} cm⁻². Vertical indexed lines mark the positions of the CF CO minima based on Eq. (1). (b) Digital derivative of the magnetoresistance for the a=150 nm sample. (c) Dingle plot of the maxima and minima of the derivative and a linear fit through the data points. The maxima and minima are referenced to the horizontal dashed line in (b) and multiplied by B^{*2} (see the text).

also observed in electron samples and was attributed to the mixing of electrostatic COs [10].

The dependence of the commensurability features on the modulation period seen in Fig. 2(a) is quite dramatic. For a=250 nm, the magnetoresistance is relatively flat, and the features appear as weak minima. As a is decreased, they become more pronounced and turn into deep minima. The V-shaped dip around $\nu=1/2$ also becomes stronger. As a is further decreased, additional, second-order (i=2) features begin to develop and become well defined in the a=175 nm sample. In the a=150 nm trace, there is even a hint of a third-order (i=3) feature as well [also see Fig. 2(b)], but the amplitude of the CO envelope decreases. The a=100 and 300 nm samples (traces not shown) exhibit no COs at all.

The above dependence of the amplitude of the CF COs on a can be qualitatively understood as follows. In the a=200 nm sample, the amplitude of the periodic surface strain is large enough to create a significant local density modulation, which in turn creates a periodic B^* and leads to strong CO features. As a increases and becomes much larger than the mean-free path of CFs, the CFs have difficulty completing cyclotron orbits. The CO features

become less pronounced, as seen in the bottom trace in Fig. 2(a), or disappear, as evidenced by the absence of COs in the a=300 nm sample [32]. When a is smaller than 200 nm, the mean-free path of the CFs should be long enough for CFs to complete a cyclotron orbit of diameter $\approx a$ without significant scattering. However, since the potential modulation created on the surface decays as $\propto \exp(-2\pi d/a)$, where d is the 2DHS depth from the sample surface, the amplitude of the local density modulation is reduced [33,34]. The reduction explains the smaller amplitude of the CF COs in the top trace in Fig. 2(a) and the absence of CO features for the a=100 nm sample.

The appearance of higher-order CO features in the a =150 nm sample allows us to estimate the CF CO lifetime and mean-free path. The digital derivative of the a =150 nm magnetoresistance (R vs B^*) trace, whose differential resistance is given in Fig. 2(a), is plotted in Fig. 2(b). The presence of a positive magnetoresistance background (as a function of B^*) upshifts the derivative so that it does not oscillate around zero. By subtracting a constant [indicated by the dashed line in Fig. 2(b)], we find the minima and maxima of the envelope of the derivative. Assuming that the oscillatory part of the CF magnetoresistance is proportional to $\exp(-\pi/\omega_C^*\tau_{CO}^{CF})$, we would expect the oscillatory part of its derivative to be $\propto (1/B^{*2}) \exp(-\pi/\omega_C^* \tau_{\rm CO}^{\rm CF})$. Here $\tau_{\rm CO}^{\rm CF}$ is the CF ballistic lifetime, $\omega_C^* = eB^*/m^*$ is the CF cyclotron frequency, *e* is the electron charge, and m^* is the effective mass of CFs [35]. In light of this relation, we plot the amplitude (the maxima and minima, referenced to the dashed line) of the Fig. 2(b) trace multiplied by B^{*2} in a Dingle-type plot [36], shown in Fig. 2(c). The error bars in the plot reflect the uncertainty in the position of the dashed line in Fig. 2(b). The linear fit on a semilogarithmic scale gives $\tau_{CO}^{CF} =$ 8 ± 1 ps. Using this value we obtain a ballistic mean-free path of $\lambda_{CO}^{CF} = 0.10 \pm 0.01 \ \mu m \ [37].$

The value of $\tau_{\text{CO}}^{\text{CF}}$ found by using this procedure is a direct determination of the CF ballistic lifetime. It falls between the values for the CF Shubnikov–de Haas lifetime $\tau_{\text{SdH}}^{\text{CF}} = 4.0$ ps we obtain from the B^* dependence of the strength of fractional quantum Hall states in the vicinity of $\nu = 1/2$ and the value of the CF transport lifetime $\tau_{\text{tr}}^{\text{CF}} = 63$ ps estimated from the resistivity value at $\nu = 1/2$. The finding that $\tau_{\text{SdH}}^{\text{CF}} < \tau_{\text{CO}}^{\text{CF}} < \tau_{\text{tr}}^{\text{CF}}$ is similar to what has been reported for electrons and holes near B = 0 [28,29] and attests to the qualitative similarity of CF transport to transport of electrons or holes. However, our result for $\tau_{\text{tr}}^{\text{CF}}$ is much larger than the previously reported value of 7.5 ps in Ref. [38] for CFs in 2DHSs grown on (113)A GaAs substrates, indicating that large-angle scattering is less prominent in our samples.

In Fig. 3(a), we present magnetoresistance traces from the a=175 nm sample as we vary the 2DHS density. The vertical lines mark the positions of the CO minima from Eq. (1). At low densities the i=1 minima are weak. As the density is increased, these minima become stronger, the

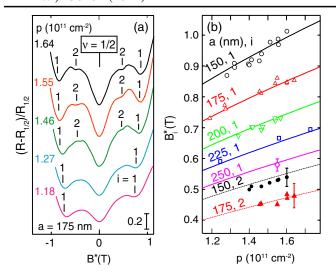


FIG. 3 (color online). (a) Magnetotransport traces of the a=175 nm sample for several densities. Indexed lines correspond to the positions of the CF CO minima expected from Eq. (1). (b) Summary of the observed positions of the $B^*>0$ CF CO minima for different periods as a function of density and their predicted positions (lines) based on Eq. (1). Representative error bars indicate the uncertainty associated with determining the positions of the weaker CF CO features.

V-shaped dip at $B^* = 0$ deepens, and i = 2 minima appear. The summary of the $B^* > 0$ positions of the CF CO resistance minima for different periods and densities for all samples is shown in Fig. 3(b). The measured positions are given with symbols. Lines indicate the expected positions in accordance with Eq. (1). The agreement of the observed minima with those predicted by Eq. (1) is remarkable.

The data presented here demonstrate robust and strong CF commensurability features in 2D hole samples subjected to a strain-induced, unidirectional, periodic potential modulation. For appropriate modulation periods, we even observe higher-order resistance oscillations near $\nu = 1/2$ that correspond to CF cyclotron orbits spanning up to three times the superlattice period. An analysis of these oscillations allows us to extract a ballistic mean-free path of about 0.1 μ m for hole-flux CFs. The higher-order CF CO minima we observe near $\nu = 1/2$ are unprecedented, as they have not been reported in 2D electron samples which typically have much higher mobilities. The exact circumstances which allow us to observe such strong CF CO features remain unclear, but they are likely related to a combination of the strength, shape, and period of the potential modulation in our samples.

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